TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WBD126FK

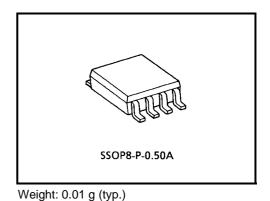
#### Dual Bus Switch with Level Shift

The TC7WBD126FK is a low on-resistance, high-speed CMOS 2-bit bus switch. This bus switch allows the connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS.

When output enable (OE) is at High level, the switch is on; when at Low level, the switch is off.

The internal diode which adds to power supply line is enable to realize the shift of signal level from 5 V to 3.3 V. (Note 1)

All inputs are equipped with protector circuits to protect the device from static discharge.



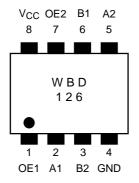
#### Features

- Operating voltage:  $V_{CC} = 4.5 \sim 5.5 V$
- High speed operation:  $t_{pd} = 0.25 \text{ ns} (\text{max})$
- Ultra-low on resistance:  $R_{ON} = 5 \Omega$  (typ.)
- Electro-static discharge (ESD) performance: ±200 V or more (JEITA)

±2000 V or more (MIL)

- TTL level input (control input)
- Package: US8
  - Note 1: In case that over-shoot noise is detected, this device should be used with clamp diode to prevent the next stage device from over-stress.

#### Pin Assignment (top view)

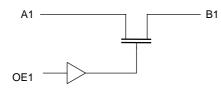


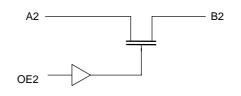
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#### **Truth Table**

| Inputs | Function        |  |  |
|--------|-----------------|--|--|
| OE     | Function        |  |  |
| L      | Disconnect      |  |  |
| Н      | A port = B port |  |  |

#### System Diagram





### **Maximum Ratings**

| Characteristics                 | Symbol                            | Rating   | Unit |  |
|---------------------------------|-----------------------------------|----------|------|--|
| Power supply range              | V <sub>CC</sub>                   | -0.5~7.0 | V    |  |
| DC input voltage                | V <sub>IN</sub>                   | -0.5~7.0 | V    |  |
| DC switch voltage               | VS                                | -0.5~7.0 | V    |  |
| Input diode current             | I <sub>IK</sub>                   | -50      | mA   |  |
| Continuous channel current      | IS                                | 128      | mA   |  |
| Power dissipation               | PD                                | 200      | mW   |  |
| DC V <sub>CC</sub> /GND current | I <sub>CC</sub> /I <sub>GND</sub> | ±100     | mA   |  |
| Storage temperature             | T <sub>stg</sub>                  | -65~150  | °C   |  |

## **Recommended Operating Conditions**

| Characteristics          | Symbol           | Rating  | Unit |
|--------------------------|------------------|---------|------|
| Supply voltage           | V <sub>CC</sub>  | 4.5~5.5 | V    |
| Input voltage            | V <sub>IN</sub>  | 0~5.5   | V    |
| Switch voltage           | VS               | 0~5.5   | V    |
| Operating temperature    | T <sub>opr</sub> | -40~85  | °C   |
| Input rise and fall time | dt/dv            | 0~10    | ns/V |

#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40~85°C)

| Character                         | istics                   | Symbol   | Test Condition                           |                          | V <sub>CC</sub> (V) | Min | Typ.<br>(Note 2) | Max  | Unit |
|-----------------------------------|--------------------------|--|--|--------------------------|---------------------|-----|------------------|------|------|
| Input voltage                     | "H" level                | VIH  | _  |                          | 4.5~5.5             | 2.0 |                  | _    | V    |
| input voltage                     | "L" level                | VIL  | _  |                          | 4.5~5.5             | _   |                  | 0.8  | v    |
| High-level output                 | voltage                  | V <sub>OH</sub>                                  | Figure 4                                 |                          | _                   | _   |                  |      |      |
| Input leakage cur                 | rent                     | I <sub>IN</sub>                                  | V <sub>IN</sub> = 0~5.5 V                |                          | 4.5~5.5             | _   | —                | ±1.0 | μA   |
| Power off leakage                 | e current                | I <sub>OFF</sub>                                 | A, B, OE = 0~5.5 V                       |                          | 0                   | _   | —                | ±1.0 | μA   |
| Off-state leakage<br>(switch off) | current                  | I <sub>SZ</sub>                                  | A, B = 0~5.5 V, OE = GND                 |                          | 4.5~5.5             | _   | _                | ±1.0 | μΑ   |
|                                   |                          |  |  | $I_{IS} = 30 \text{ mA}$ | 4.5                 | _   | 5                | 7    |      |
| ON resistance                     | (Note 3)                 | (Note 2) R <sub>ON</sub>                         | $V_{IS} = 0 V$                           | $I_{IS} = 64 \text{ mA}$ | 4.5                 | _   | 5                | 7    | Ω    |
| (Note 3)                          |                          | $V_{IS} = 2.4 \text{ V}, I_{IS} = 15 \text{ mA}$ |  | 4.5                      | _                   | 35  | 50               |      |      |
|                                   |                          | laa  | V <sub>IN</sub> = V <sub>CC</sub> or GND | Switch ON                | 5.5                 | _   | —                | 1.5  | mA   |
| Quiescent supply                  | Quiescent supply current |  | $I_{OUT} = 0$                            | Switch OFF               | 5.5                 | _   | —                | 10   | μA   |
|                                   |                          | $\Delta I_{CC}$                                  | $V_{IN} = 3.4 \text{ V}$ (one input)     | (Note 4)                 | 5.5                 | _   | —                | 2.5  | mA   |

Note 2: Typical values are at  $V_{CC} = 5 V$  and  $Ta = 25^{\circ}C$ .

Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 4: Quiescent supply current at V<sub>CC</sub> = 3.4 V will be sum of I<sub>CC</sub> and  $\Delta$ I<sub>CC</sub>.

#### AC Characteristics (Ta = -40~85°C)

| Characteristics                        | Symbol                               | Test Condition              | V <sub>CC</sub> (V) | Min | Max  | Unit |
|--|--------------------------------------|-----------------------------|---------------------|-----|------|------|
| Propagation delay time<br>(bus to bus) | t <sub>pLH</sub><br>t <sub>pHL</sub> | Figure 1, Figure 2 (Note 5) | 4.5                 |     | 0.25 | ns   |
| Output enable time                     | t <sub>pZL</sub><br>t <sub>pZH</sub> | Figure 1, Figure 3          | 4.5                 | _   | 4.5  | ns   |
| Output disable time                    | t <sub>pLZ</sub><br>t <sub>pHZ</sub> | Figure 1, Figure 3          | 4.5                 |     | 5.5  | ns   |

Note 5: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

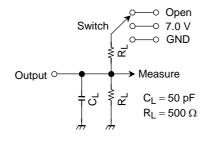
#### **Capacitive Characteristics (Ta = 25°C)**

| Characteristics               | Symbol           | Test Condition | V <sub>CC</sub> (V) | Тур. | Unit |
|-------------------------------|------------------|----------------|---------------------|------|------|
| Control pin input capacitance | C <sub>IN</sub>  | (Note          | 6) 5.0              | 3    | pF   |
| Switch terminal capacitance   | C <sub>I/O</sub> | OE = GND (Note | 6) 5.0              | 10   | pF   |

Note 6: This parameter is guaranteed by design.

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#### **AC Test Circuit**



| Parameter                           | Switch |
|-------------------------------------|--------|
| t <sub>pLH</sub> , t <sub>pHL</sub> | Open   |
| t <sub>pLZ</sub> , t <sub>pZL</sub> | 7.0 V  |
| t <sub>pHZ</sub> , t <sub>pZH</sub> | Open   |



#### **AC Waveform**

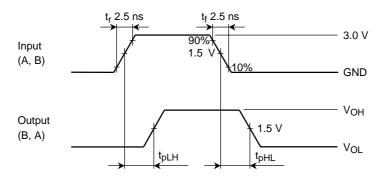
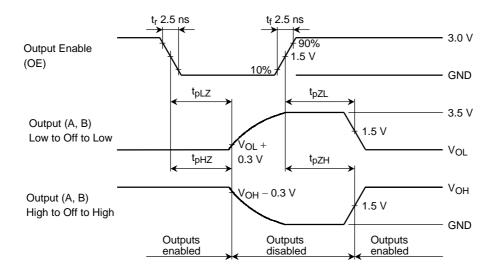
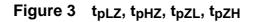
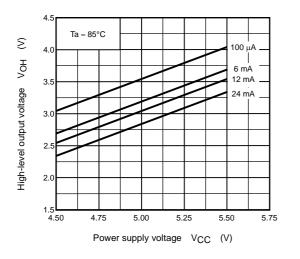


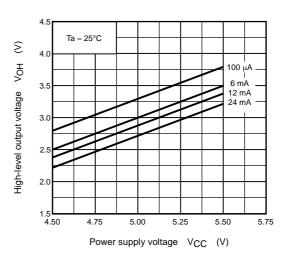
Figure 2  $t_{pLH}, t_{pHL}$ 





### V<sub>OH</sub> – V<sub>CC</sub> Characteristics (typ.)





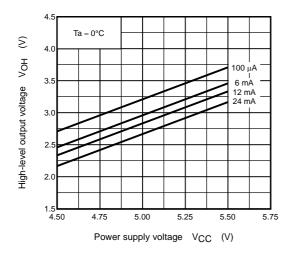


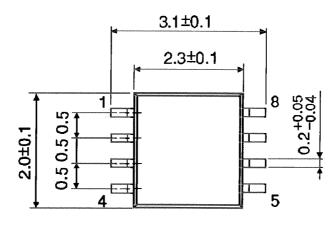
Figure 4

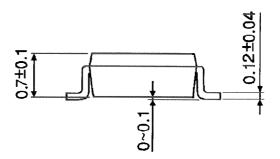
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### Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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